



Applications

- Phase Control
- Static Switching
- Light Dimming
- Motor Speed Control
- Kitchen Equipment
- Power Tools
- Solenoid Valve Controls:
 - Dishwashers
 - Washing Machines

- Suitable for General Purpose AC Switching
- Alternistor/No Snubber Versions for Inductive Loads
- Logic Level Available for Use with Microcontrollers and Low Level Devices
- IGT Range 5-50 mA (Q1)
- V_{DRM}/V_{RMM} 400, 600, 800, 1000V

Absolute Maximum Ratings

	CONDITIONS	SYMBOL	RATING
RMS On-State Current (full sine wave)	$T_c = 110^\circ\text{C}$ $T_c = 105^\circ\text{C}$	TO-220AB TO-220AB Iso $I_{T(RMS)}$	6A
Non Repetitive Surge Peak On-State Current (Full Cycle, T_j Initial = 25°C)	F = 50 Hz F = 60 Hz	I_{TSM}	60A 63A
I^2t Value for fusing	$t_p = 10$ ms	I^2t	21A ² s
Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r < 100$ ns, $T_j = 125^\circ\text{C}$	F = 120 Hz	di/dt	100A/ μ s
Peak Gate Current @ $T_j = 125^\circ\text{C}$	$t_p = 20$ μ s	I_{GM}	4A
Average Gate Power Dissipation @ $T_j = 125^\circ\text{C}$		$P_{G(AV)}$	1W
Storage Temperature Range		T_{stg}	-40 to +150°C
Operating Junction Temperature Range		T_j	-40 to +125°C
Isolation Voltage (CTA Series only)		V_{ISO}	2500 V_{RMS}

Electrical Characteristics

ALTERNISTOR/NO SNUBBER AND LOGIC LEVEL (3 Quadrants)

I_{GT} MAX @ $V_D = 12$ V, $R_L = 30\Omega$ NOTE 1	QI-II-III	5mA	10mA	35mA	50mA
V_{GT} MAX @ $V_D = 12$ V, $R_L = 30\Omega$	QI-II-III	1.3V	1.3V	1.3V	1.3V
V_{GD} MIN @ $V_D = V_{DRM}$, $R_L = 3.3k\Omega$	$T_J = 125^\circ\text{C}$ QI-II-III	0.2V	0.2V	0.2V	0.2V
I_H MAX @ $I_T = 500$ mA NOTE 2		10mA	15mA	35mA	50mA
I_L MAX @ $I_G = 1.2 I_{GT}$	QI-III	10mA	25mA	50mA	70mA
I_L MAX @ $I_G = 1.2 I_{GT}$	Q-II	15mA	30mA	60mA	80mA
dv/dt MIN @ $V_D = 67\%V_{DRM}$ (gate open) NOTE 2	$T_J = 125^\circ\text{C}$	20V/ μs	40V/ μs	400V/ μs	1000V/ μs
$(di/dt)_c$ MIN @ $(dv/dt)_c = 0.1$ V/ms NOTE 2	$T_J = 125^\circ\text{C}$	2.7A/ms	3.5A/ms		
$(di/dt)_c$ MIN @ $(dv/dt)_c = 10$ V/ms NOTE 2	$T_J = 125^\circ\text{C}$	1.2A/ms	2.4A/ms		
$(di/dt)_c$ MIN without Snubber NOTE 2 & 4	$T_J = 125^\circ\text{C}$			3.5A/ms	5.3A/ms

STANDARD (4 Quadrants)

I_{GT} MAX @ $V_D = 12$ V, $R_L = 30\Omega$ NOTE 1	QI-II-III	25mA	50mA
I_{GT} MAX @ $V_D = 12$ V, $R_L = 30\Omega$ NOTE 1	QIV	50mA	100mA
V_{GT} MAX @ $V_D = 12$ V, $R_L = 30\Omega$	Q-All	1.3V	
V_{GD} MIN @ $V_D = V_{DRM}$, $R_L = 3.3k\Omega$ $T_J = 125^\circ C$	Q-All	0.2V	
I_H MAX @ $I_T = 500$ mA NOTE 2		25mA	50mA
I_L MAX @ $I_G = 1.2 I_{GT}$	QI-III-IV	40mA	50mA
I_L MAX @ $I_G = 1.2 I_{GT}$	Q-II	80mA	100mA
dv/dt MIN @ $V_D = 67\%V_{DRM}$ (gate open) NOTE 2 $T_J = 125^\circ C$		200V/ μs	400V/ μs
$(dv/dt)_c$ MIN @ $(di/dt)_c = 2.7$ A/ms NOTE 2 & 4 $T_J = 125^\circ C$		5V/ μs	10V/ μs

GENERAL NOTES

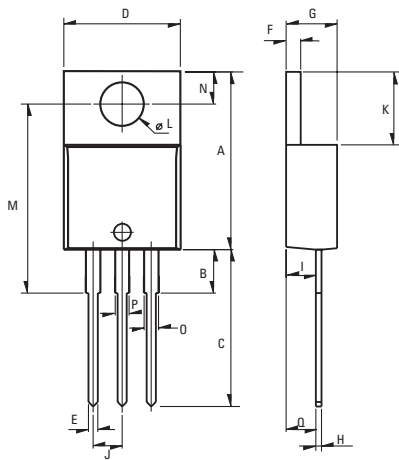
1. Minimum IGT is guaranteed at 5% of IGT max.
2. For both polarities of A2 referenced to A1
3. All parameters at 25 degrees C unless otherwise specified.
4. Commutating $dv/dt = 50V/\mu$ sec (exponential to 200Vpk)

Static Characteristics

V_T MAX @ $I_{TM} = 5.5$ A, $t_p = 380\mu s$ NOTE 2	$T_J = 25^\circ C$	1.55V
V_{TO} MAX @ Threshold Voltage NOTE 2	$T_J = 125^\circ C$	0.85V
R_d MAX @ Dynamic Resistance NOTE 2	$T_J = 125^\circ C$	60m Ω
I_{DRM} MAX @ $V_{DRM} = V_{RRM}$	$T_J = 25^\circ C$	5 μ A
I_{RRM} MAX @ $V_{DRM} = V_{RRM}$	$T_J = 125^\circ C$	1mA

Thermal Resistances

		SYMBOL	RATING
Junction to Case (AC)	TO-220AB	$R_{th(j-c)}$	1.8°C/W
Junction to Case (AC)	TO-220AB Isolated	$R_{th(j-c)}$	2.7°C/W
Junction to Ambient	TO-220AB	$R_{th(j-a)}$	60°C/W
Junction to Ambient	TO-220AB Isolated	$R_{th(j-a)}$	60°C/W



Weight: 2.3g (0.08 oz)

Dimensions

REF.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.24		15.75	0.6		0.62
B		3.23			0.127	
C	12.78		13.79	0.503		0.543
D	9.96		10.36	0.392		0.408
E	0.69		0.94	0.027		0.037
F	1.22		1.32	0.048		0.052
G	4.62		4.83	0.182		0.19
H	0.46		0.61	0.018		0.024
I	2.49		2.84	0.098		0.112
J	2.39		2.69	0.094		0.106
K	6.48		6.88	0.255		0.271
L	3.78		3.89	0.149		0.153
M	15.49	16	16.51	0.61	0.63	0.65
N	2.59		2.9	0.102		0.114
O	0.99		1.55	0.039		0.061
P	0.99		1.55	0.039		0.061
Q		2.67			0.105	

Part Number Selection

Part Number	Voltage [Vpk]	I_{GT} [mA]	Type	Package
CTA/CTB06-xxxB	400, 600, 800, 1000	50mA	Standard	TO-220AB
CTA/CTB06-xxxBW	400, 600, 800, 1000	50mA	Alternistor/No Snubber	TO-220AB
CTA/CTB06-xxxC	400, 600, 800, 1000	25mA	Standard	TO-220AB
CTA/CTB06-xxxCW	400, 600, 800, 1000	35mA	Alternistor/No Snubber	TO-220AB
CTA/CTB06-xxxSW	400, 600, 800, 1000	10mA	Logic Level	TO-220AB
CTA/CTB06-xxxTW	400, 600, 800, 1000	5mA	Logic Level	TO-220AB

Part Number Designation

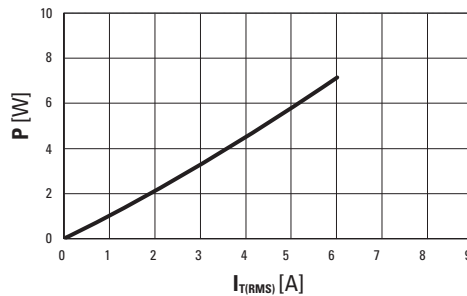
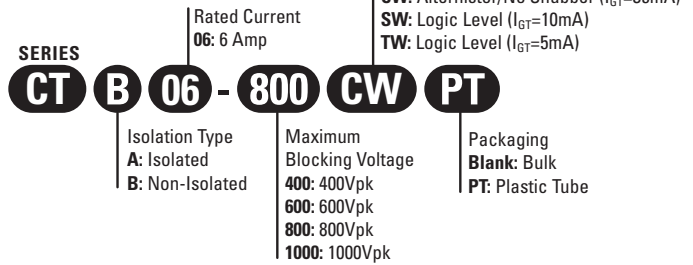


Fig. 1: Power dissipation versus RMS on-state current (full cycle).

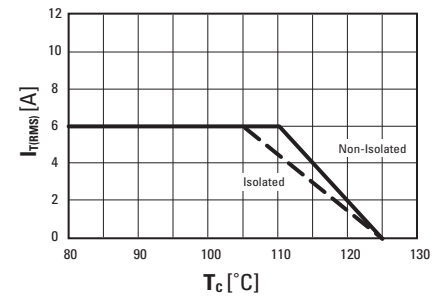


Fig. 2: RMS on-state current versus case temperature (full cycle)

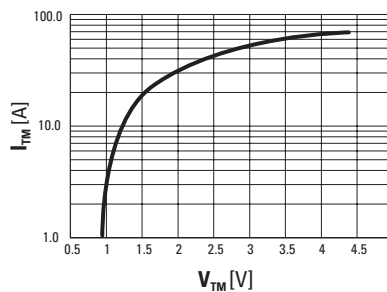


Fig. 3: On-state current versus on-state voltage (instantaneous values)

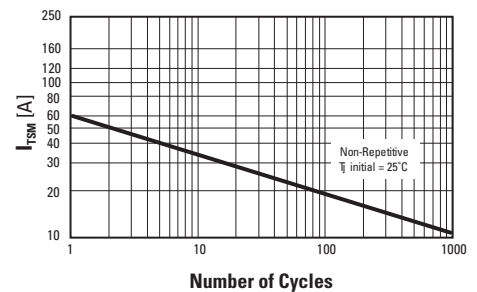


Fig. 4: Non-repetitive surge peak on-state current versus number of cycles.

ISO9001 CERTIFIED

Approvals

UL Recognized Component - E72445 (CTA Series)

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